



CHENMKO ENTERPRISE CO.,LTD

CH521G-30PT

SURFACE MOUNT

SCHOTTKY BARRIER DIODE

VOLTAGE 30 Volts CURRENT 0.2 Ampere

Lead free devices

APPLICATION

* Low current rectification and high speed switching

FEATURE

- * Extremely small surface mounting type. (SOD-723)
- * $I_o=200mA$ guaranteed despite size
- * Low VF. (VF=0.40V Typ. at 200mA)

CONSTRUCTION

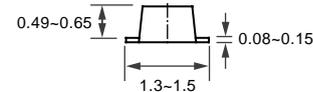
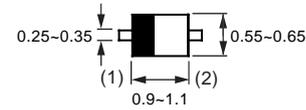
* Silicon epitaxial planar

MARKING

* 3



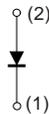
SOD-723



Dimensions in millimeters

SOD-723

CIRCUIT



MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	CH521G-30PT	UNITS
Maximum Recurrent Peak Reverse Voltage	VRRM	30	Volts
Maximum RMS Voltage	VRMS	21	Volts
Maximum DC Blocking Voltage	VDC	30	Volts
Maximum Average Forward Rectified Current	I_o	0.2	Amps
Peak Forward Surge Current at 8.3 mSec single half sine-wave	IFSM	1.0	Amps
Typical Junction Capacitance between Terminal (Note 1)	CJ	6.0	pF
Maximum Operating Temperature Range	TJ	+125	°C
Storage Temperature Range	TSTG	-40 to +125	°C

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	CH521G-30PT	UNITS
Maximum Instantaneous Forward Voltage at $I_f=200mA$	VF	0.50	Volts
Maximum Average Reverse Current at $V_R=10V$	IR	30.0	uAmps

NOTES : 1. Measured at 1.0 MHz and applied reverse voltage of 10 volts.
 2. ESD sensitive product handling required.

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RATING CHARACTERISTIC CURVES (CH521G-30PT)

FIG. 1 - FORWARD CHARACTERISTICS

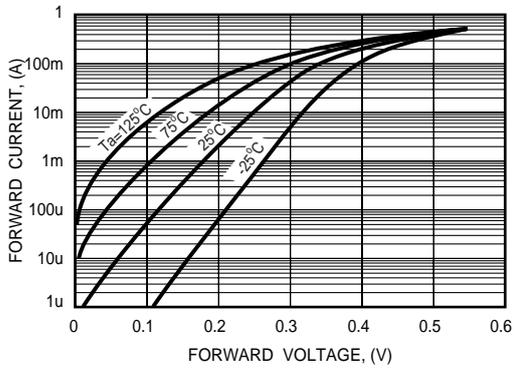


FIG. 2 - REVERSE CHARACTERISTICS

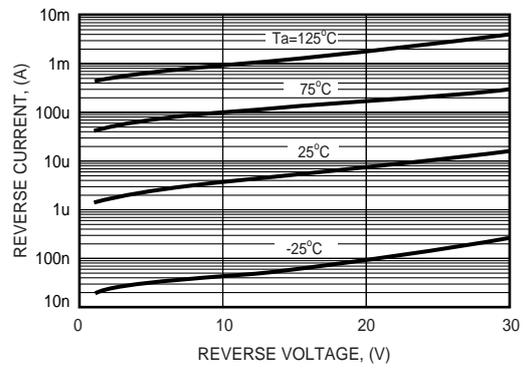


FIG. 3 - TYPICAL JUNCTION CAPACITANCE

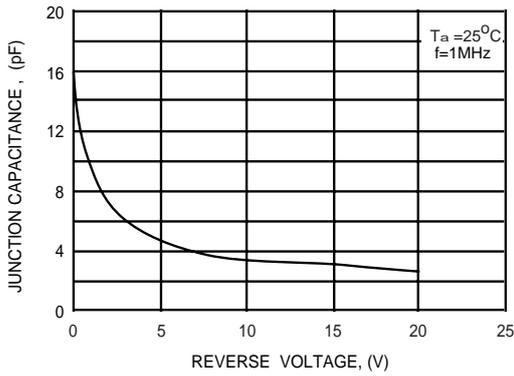


FIG. 4 - TYPICAL FORWARD CURRENT DERATING CURVE

